High Speed Quad-Channel Digital Isolator

Product Preview

NCID9401, NCID9411

Description

The NCID94xx is a galvanically isolated high-speed quad-channel digital isolator with output enable. This device supports isolated communications thereby allowing digital signals to communicate between systems without conducting ground loops or hazardous voltages.

It utilizes ON Semiconductor's patented galvanic off-chip capacitor isolation technology and optimized IC design to achieve high insulation and high noise immunity, characterized by high common mode rejection and power supply rejection specifications. The thick ceramic substrate yields capacitors with ~25 times the thickness of thin film on-chip capacitors and coreless transformers. The result is a combination of the electrical performance benefits that digital isolators offer with the safety reliability of a >0.5 mm insulator barrier similar to what has historically been offered by optocouplers.

The device is housed in a 16-pin wide body small outline package.

Features

- Off-Chip Capacitive Isolation to Achieve Reliable High Voltage Insulation
 - DTI (Distance Through Insulation): ≥ 0.5 mm
 - ♦ Maximum Working Insulation Voltage: 2000 V_{peak}
- Bi-directional Communication
- 100 kV/µs Minimum Common Mode Rejection
- 8 mm Creepage and Clearance Distance to Achieve Reliable High Voltage Insulation
- Specifications Guaranteed Over 2.5 V to 5.5 V Supply Voltage and -40°C to 125°C Extended Temperature Range
- Over Temperature Detection
- Output Enable Function (Primary and Secondary side)
- NCIV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable (Pending)
- Safety and Regulatory Approvals
 - UL1577, 5000 VRMS for 1 Minute
 - DIN VDE V 0884-11 (Pending)

Typical Applications

- Isolated PWM Control
- Industrial Fieldbus Communications
- Microprocessor System Interface (SPI, I²C, etc.)
- Programmable Logic Control
- Isolated Data Acquisition System
- Voltage Level Translator

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.



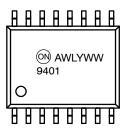
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SOIC16 W CASE 751EN

MARKING DIAGRAM



= Assembly Location = Wafer Lot / Assembly Lot

WL = Wafer Lot / Assembly = Year

WW = Work Week

Α

9401/9411 = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 13 of this data sheet.

BLOCK DIAGRAM

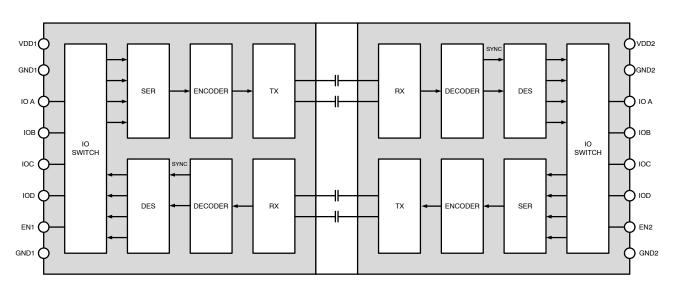


Figure 1. Functional Block Diagram

PIN CONFIGURATION

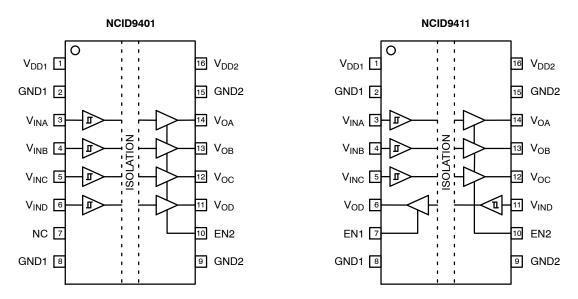


Figure 2. Pin and Channel Configuration

PIN DEFINITION

Name	Pin No. NCID9401	Pin No. NCID9411	Description
V _{DD1}	1	1	Power Supply, Side 1
GND1	2	2	Ground Connection for V _{DD1}
V _{INA}	3	3	Input, Channel A
V _{INB}	4	4	Input, Channel B
V _{INC}	5	5	Input, Channel C
V _{IND}	6	11	Input, Channel D
EN1	-	7	Output Enable 1
GND1	8	8	Ground Connection for V _{DD1}
GND2	9	9	Ground Connection for V _{DD2}
EN2	10	10	Output Enable 2
V _{OD}	11	6	Output, Channel D
V _{OC}	12	12	Output, Channel C
V _{OB}	13	13	Output, Channel B
V _{OA}	14	14	Output, Channel A
GND2	15	15	Ground Connection for V _{DD2}
V _{DD2}	16	16	Power Supply, Side 2
NC	7	-	No Connect

SPECIFICATIONS

TRUTH TABLE (Note 1)

V _{INX}	EN _X	V _{DDI}	V _{DDO}	V _{ox}	Comment
Н	H/NC	Power Up	Power Up	Н	Normal Operation
L	H/NC	Power Up	Power Up	L	Normal Operation
Х	L	Power Up	Power Up	Hi–Z	
Х	H/NC	Power Down	Power Up	L	Default low; V _{OX} return to normal operation when V _{DDI} change to Power Up
Х	H/NC	Power Up	Power Down	Undetermined (Note 2)	V_{OX} return to normal operation when V_{DDO} change to Power Up

VINX = Input signal of a given channel (A, B, C or D). EN_X = Enable pin for primary or secondary side (1 or 2). V_{OX} = Output signal of a given channel (A, B, C or D). V_{DDI} = Input-side V_{DD}. V_{DDO} = Output-side V_{DD}. X = Irrelevant. H = High level. L = Low level. NC = No Connection.
 The outputs are in undetermined state when V_{DDO} < V_{UVLO}.

SAFETY AND INSULATION RATINGS

As per DIN VDE V 0884-11, this digital isolator is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings must be ensured by means of protective circuits.

Symbol	Parameter		Min	Тур	Max	Unit
	Installation Classifications per DIN VDE 0110/1.89	-	I–IV	-		
	Table 1 Rated Mains Voltage	< 300 V _{RMS}	=	I–IV	-	
		< 450 V _{RMS}	-	I–IV	-	
		< 600 V _{RMS}	-	I–IV	-	
		< 1000 V _{RMS}	-	I–III	-	
	Climatic Classification		=	40/100/21	-	
	Pollution Degree (DIN VDE 0110/1.89)		=	2	-	
CTI	Comparative Tracking Index (DIN IEC 112/VDE 0303	Part 1)	600	=	-	
V _{PR}	Input–to–Output Test Voltage, Method b, $V_{IORM} \times 1.8$ Production Test with $t_m = 1$ s, Partial Discharge < 5 p	3750	-	-	V _{peak}	
	Input-to-Output Test Voltage, Method a, $V_{IORM} \times 1.6$ and Sample Test with $t_m = 10$ s, Partial Discharge < 6	3200	-	_	V _{peak}	
V _{IORM}	Maximum Working Insulation Voltage		2000	-	-	V_{peak}
V _{IOTM}	Highest Allowable Over Voltage		8000	-	-	V_{peak}
E _{CR}	External Creepage		8.0	-	-	mm
E _{CL}	External Clearance		8.0	-	-	mm
DTI	Insulation Thickness		0.50	-	-	mm
T _{Case}	Safety Limit Values – Maximum Values in Failure; Ca	150	-	-	°C	
P _{S,INPUT}	Safety Limit Values – Maximum Values in Failure; Inp	Limit Values – Maximum Values in Failure; Input Power		-	-	mW
P _{S,OUTPUT}	Safety Limit Values – Maximum Values in Failure; Ou	tput Power	600	-	-	mW
R _{IO}	Insulation Resistance at TS, V _{IO} = 500 V		10 ⁹	-	-	Ω

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit
T _{STG}	Storage Temperature	-55 to +150	°C
T _{OPR}	Operating Temperature	-40 to +125	°C
T_J	Junction Temperature	-40 to +150	°C
T _{SOL}	Lead Solder Temperature (Refer to Reflow Temperature Profile)	260 for 10 s	°C
V_{DD}	Supply Voltage (V _{DDx})	–0.5 to 6	V
V	Voltage (V _{INx} , V _{Ox} , ENx)	–0.5 to 6	V
lo	Average Output Current	15	mA
PD	Power Dissipation	210	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING RANGES

Symbol	Parameter	Min	Max	Unit
T _A	Ambient Operating Temperature	-40	+125	°C
V _{DD1} V _{DD2}	Supply Voltage (Notes 3, 4)	2.5	5.5	V
V _{INH}	High Level Input Voltage	$0.7 \times V_{DDI}$	V_{DDI}	V
V _{INL}	Low Level Input Voltage	0	$0.3 \times V_{DDI}$	V
V _{UVLO+}	Supply Voltage UVLO Rising Threshold	2.2	-	V
V _{UVLO} _	Supply Voltage UVLO Falling Threshold	2.0	-	V
UVLO _{HYS}	Supply Voltage UVLO Hysteresis	0.1	-	V
Іон	High Level Output Current	-2	-	mA
I _{OL}	Low Level Output Current	_	2	mA
DR	Signaling Rate	0	10	Mbps

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ISOLATION CHARACTERISTICS

Apply over all recommended conditions. All typical values are measured at $T_A = 25$ °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{ISO}	Input-Output Isolation Voltage	T_A = 25°C, Relative Humidity < 50%, t = 1.0 minute, $I_{I-O} \leq$ 10 $\mu A,$ 50 Hz (Notes 5, 6, 7)	5000	-	1	V _{RMS}
R _{ISO}	Isolation Resistance	V _{I-O} = 500 V (Note 5)	-	10 ¹¹	-	
C _{ISO}	Isolation Capacitance	V _{I-O} = 0 V, Frequency = 1.0 MHz (Note 5)	-	1	-	pF

^{5.} Device is considered a two-terminal device: pins 1 to 8 are shorted together and pins 9 to 16 are shorted together.

^{3.} During power up or down, ensure that both the input and output supply voltages reach the proper recommended operating voltages to avoid any momentary instability at the output state.

For reliable operation at recommended operating conditions, V_{DD} supply pins require at least a pair of external bypass capacitors, placed within 2 mm from V_{DD} pins 1 and 16 and GND pins 2 and 15. Recommended values are 0.1 μF and 1 μF.

^{6. 5,000} V_{RMS} for 1-minute duration is equivalent to 6,000 V_{RMS} for 1-second duration.

^{7.} The input-output isolation voltage is a dielectric voltage rating per UL1577. It should not be regarded as an input-output continuous voltage rating. For the continuous working voltage rating, refer to equipment-level safety specification or DIN VDE V 0884-11 Safety and Insulation Ratings Table on page 4.

ELECTRICAL CHARACTERISTICS

Apply over all recommended conditions, $T_A = -40$ °C to +125°C, $V_{DD1} = V_{DD2} = 2.5$ V to 5.5 V, unless otherwise specified. All typical values are measured at $T_A = 25$ °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Figure
V _{OH}	High Level Output	$V_{DD} = 5 \text{ V}, I_{OH} = -4 \text{ mA}$	V _{DDO} – 0.4	V _{DDO} – 0.1	-	V	11
	Voltage	$V_{DD} = 3.3 \text{ V}, I_{OH} = -2 \text{ mA}$					
		V _{DD} = 2.5 V, I _{OH} = -1 mA					
V_{OL}	Low Level Output	V _{DD} = 5 V, I _{OL} = 4 mA	-	0.1	0.4	V	12
	Voltage	V _{DD} = 3.3 V, I _{OL} = 2 mA					
		V _{DD} = 2.5 V, I _{OL} = 1 mA					
V_{INT+}	Rising Input Voltage Threshold		-	-	$0.7 \times V_{DDI}$	V	
V_{INT-}	Falling Input Voltage Threshold		$0.1 \times V_{DDI}$	-	-	V	
V _{INT(HYS)}	Input Threshold Voltage Hysteresis		$0.1 \times V_{DDI}$	$0.2 \times V_{DDI}$	-	V	
I _{INH}	High Level Input Current	$V_{IH} = V_{DDI}$	-	-	1	μΑ	
I _{INL}	Low Level Input Current	V _{IL} = 0 V	-1	-	-	μΑ	
CMTI	Common Mode Transient Immunity	V _I = V _{DDI} or 0 V, V _{CM} = 1500 V	100	150	-	kV/μs	16
C _{IN}	Input Capacitance	$\begin{aligned} V_{IN} &= V_{DDI}/2 + 0.4 \times \text{sin } (2\pi \text{ft}), \\ f &= 1 \text{ MHz}, V_{DD} = 5 \text{ V} \end{aligned}$	-	2	-	pF	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

SUPPLY CURRENT CHARACTERISTICS

Apply over all recommended conditions, $T_A = -40^{\circ}C$ to $+125^{\circ}C$ unless otherwise specified. All typical values are measured at $T_A = 25^{\circ}C$.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Figure
I _{DD1}	DC Supply Current	$V_{DD} = 5 \text{ V, EN} = 0/5 \text{ V,}$	_	8.3	11.3	mA	
I _{DD2}		$V_{IN} = 0/5 V$		9.3	12.3		
I _{DD1}		V _{DD} = 3.3 V, EN = 0/3.3 V,		8.0	11		
I _{DD2}		$V_{IN} = 0/3.3 \text{ V}$		9.1	12		
I _{DD1}		$V_{DD} = 2.5 \text{ V, EN} = 0/2.5 \text{ V,}$ $V_{IN} = 0/2.5 \text{ V}$		7.9	10.8		
I _{DD2}		V _{IN} = 0/2.5 V		9.0	11.8		
I _{DD1}	AC Supply Current 1 Mbps	V _{DD} = 5 V, EN = 5 V, C _I = 15 pF,	_	8.4	11.3	mA	3, 4, 5, 6
I _{DD2}	Т Мирь	V _{IN} = 5 V Square Wave		9.5	12.3		5, 0
I _{DD1}	7	V _{DD} = 3.3 V, EN = 3.3 V,		8.1	11		
I _{DD2}		C _L = 15 pF, V _{IN} = 3.3 V Square Wave		9.2	12		
I _{DD1}		V _{DD} = 2.5 V, EN = 2.5 V,	1	8.0	10.8		
I _{DD2}	7	$C_L = 15 \text{ pF},$ $V_{IN} = 2.5 \text{ V Square Wave}$		9.1	11.8		
I _{DD1}	AC Supply Current	V _{DD} = 5 V, EN = 5 V,	-	8.9	12.6	mA	
I _{DD2}	— 10 Mbps	C _L = 15 pF, V _{IN} = 5 V Square Wave		11.3	13.6	1	
I _{DD1}		V _{DD} = 3.3 V, EN = 3.3 V,	1	8.4	11.7		
I _{DD2}		C _L = 15 pF, V _{IN} = 3.3 V Square Wave		10.2	12.7		
I _{DD1}	7	V _{DD} = 2.5 V, EN = 2.5 V, C _I = 15 pF,		8.2	11.3		
I _{DD2}	1	V _{IN} = 2.5 V Square Wave		9.8	12.3		

SWITCHING CHARACTERISTICS - NCID9401

Apply over all recommended conditions, $T_A = -40^{\circ}C$ to $+125^{\circ}C$ unless otherwise specified. All typical values are measured at $T_A = 25^{\circ}C$.

Symbol	Parameter	Ch	Conditions	Min	Тур	Max	Unit	Figure		
t _{PHL}	Propagation Delay to Logic Low	All	V _{DD} = 5 V, C _L = 15 pF	-	136	200	ns	8, 13		
	Output (Note 8)		V _{DD} = 3.3 V, C _L = 15 pF							
			V _{DD} = 2.5 V, C _L = 15 pF							
t _{PLH}	Propagation Delay to Logic High	All	V _{DD} = 5 V, C _L = 15 pF	-	137	200	ns	1		
	Output (Note 9)		V _{DD} = 3.3 V, C _L = 15 pF							
			V _{DD} = 2.5 V, C _L = 15 pF	7						
PWD	Pulse Width Distortion	All	V _{DD} = 5 V, C _L = 15 pF	=	33	80	ns			
	t _{PHL} – t _{PLH} (Note 10)		V _{DD} = 3.3 V, C _L = 15 pF	7						
			V _{DD} = 2.5 V, C _L = 15 pF	7						
t _{PSK(PP)}	Propagation Delay Skew	All	V _{DD} = 5 V, C _L = 15 pF	-80	-	80	ns			
	(Part to Part) (Note 11)		V _{DD} = 3.3 V, C _L = 15 pF	7						
			V _{DD} = 2.5 V, C _L = 15 pF	7						
t _R	Output Rise Time (10% to 90%)	All	V _{DD} = 5 V, C _L = 15 pF	=	3	3	3	-	ns	
			V _{DD} = 3.3 V, C _L = 15 pF							
			V _{DD} = 2.5 V, C _L = 15 pF							
t _F	Output Fall Time (90% to 10%)	All	V _{DD} = 5 V, C _L = 15 pF	_	2	_	ns			
			V _{DD} = 3.3 V, C _L = 15 pF							
			V _{DD} = 2.5 V, C _L = 15 pF							
t _{PZL}	High Impedance to Logic Low	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	8.4	25	ns	14		
	Output Delay (Note 12)		V_{DD} = 3.3 V, R_L = 1 k Ω		9.9					
			V_{DD} = 2.5 V, R_L = 1 k Ω		12.3					
t_{PLZ}	Logic Low to High Impedance	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	10.8	25	ns			
	Output Delay (Note 13)		V_{DD} = 3.3 V, R_L = 1 k Ω		14.5					
			V_{DD} = 2.5 V, R_L = 1 k Ω		17.8					
t _{PZH}	High Impedance to Logic High	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	0.53	1	μs	15		
	Output Delay (Note 14)		V_{DD} = 3.3 V, R_L = 1 k Ω		0.50					
			V_{DD} = 2.5 V, R_L = 1 k Ω		0.50					
t _{PHZ}	Logic High to High Impedance	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	-	11.7	25	ns]		
	Output Delay (Note 15)		V_{DD} = 3.3 V, R_L = 1 k Ω		13.1					
			V_{DD} = 2.5 V, R_L = 1 k Ω		15.0					

^{8.} Propagation delay t_{PHL} is measured from the 50% level of the falling edge of the input pulse to the 50% level of the falling edge of the V_O signal.

^{9.} Propagation delay t_{PLH} is measured from the 50% level of the rising edge of the input pulse to the 50% level of the rising edge of the V_O signal. 10. PWD is defined as $|t_{PHL} - t_{PLH}|$ for any given device.

^{11.} Part-to-part propagation delay skew is the difference between the measured propagation delay times of a specified channel of any two parts at identical operating conditions and equal load.

^{12.} Enable delay t_{PZL} is measured from the 50% level of the rising edge of the EN pulse to the 50% of the falling edge of the V_O signal as it switches from high impedance state to low state.

^{13.} Disable delay t_{PLZ} is measured from the 50% level of the falling edge of the EN pulse to 0.5 V level of the rising edge of the V_O signal as it switches from low state to high impedance state.

^{14.} Enable delay t_{PZH} is measured from the 50% level of the rising edge of the EN pulse to the 50% of the rising edge of the V_O signal as it switches from high impedance state to high state.

^{15.} Disable delay t_{PHZ} is measured from the 50% level of the falling edge of the EN pulse to V_{OH} – 0.5 V level of the falling edge of the V_{O} signal as it switches from high state to high impedance state.

SWITCHING CHARACTERISTICS - NCID9411

Apply over all recommended conditions, $T_A = -40^{\circ}C$ to $+125^{\circ}C$ unless otherwise specified. All typical values are measured at $T_A = 25^{\circ}C$.

Symbol	Parameter	Ch	Conditions	Min	Тур	Max	Unit	Figure												
	Propagation Delay to Logic	A, B, C	V _{DD} = 5 V, C _L = 15 pF	-	115	170	ns	9, 10, 13												
	Low Output (Note 8)		V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
		D	V _{DD} = 5 V, C _L = 15 pF	-	77	110	ns	7												
			V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
t _{PLH}	Propagation Delay to Logic	A,B,C	V _{DD} = 5 V, C _L = 15 pF	-	117	170	ns	7												
	High Output (Note 9)		V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
		D	V _{DD} = 5 V, C _L = 15 pF	-	78	110	ns	7												
			V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
PWD	Pulse Width Distortion	A,B,C	V _{DD} = 5 V, C _L = 15 pF	-70	26	70	ns	1												
	t _{PHL} – t _{PLH} (Note 10)		V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
		D	V _{DD} = 5 V, C _L = 15 pF	-40	13	13	13	13	13	13	13	13	13	13	13	13	13	40	ns	
			V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
t _{PSK(PP)}	Propagation Delay Skew	All	V _{DD} = 5 V, C _L = 15 pF	-70	-70	70	ns	1												
	(Part to Part) (Note 11)		V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
t _R	Output Rise Time	All	V _{DD} = 5 V, C _L = 15 pF	-	3	-	ns	1												
	(10% to 90%)		V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
t _F	Output Fall Time	All	V _{DD} = 5 V, C _L = 15 pF	_	2	_	ns	1												
	(90% to 10%)		V _{DD} = 3.3 V, C _L = 15 pF																	
			V _{DD} = 2.5 V, C _L = 15 pF																	
t _{PZL}	High Impedance to Logic	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	8.5	25	ns	14												
	Low Output Delay (Note 12)		V _{DD} = 3.3 V, R _L = 1 kΩ		10.2	1														
			$V_{DD} = 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$		12.6	1														
t _{PLZ}	Logic Low to High Impedance	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	10.8	25	ns	1												
	Output Delay (Note 13)		$V_{DD} = 3.3 \text{ V, R}_{L} = 1 \text{ k}\Omega$	_	14.6	1														
			$V_{DD} = 2.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$		17.8	1														
t _{PZH}	High Impedance to Logic High	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	0.54	1	μS	15												
	Output Delay (Note 14)		$V_{DD} = 3.3 \text{ V}, R_{L} = 1 \text{ k}\Omega$		0.50	1														
			$V_{DD} = 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$		0.50															
t _{PHZ}	Logic High to High Impedance	All	$V_{DD} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	_	11.6	25	ns	-												
1112	Output Delay (Note 15)		$V_{DD} = 3.3 \text{ V}, R_L = 1 \text{ k}\Omega$		12.9	1														
			$V_{DD} = 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$	\dashv	14.6	1														

TYPICAL PERFORMANCE CHARACTERISTICS

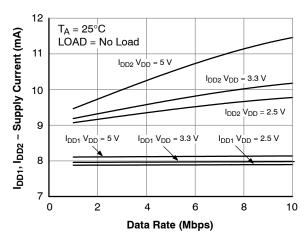


Figure 3. NCID9401 Supply Current vs. Data Rate (No Load)

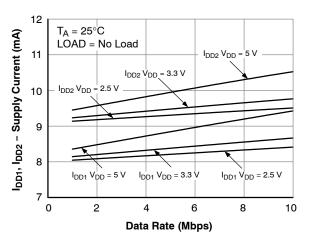


Figure 5. NCID9411 Supply Current vs. Data Rate (No Load)

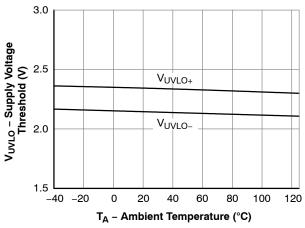


Figure 7. Supply Voltage UVLO Threshold vs.

Ambient Temperature

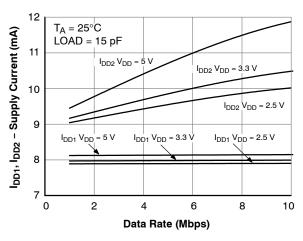


Figure 4. NCID9401 Supply Current vs. Data Rate (Load = 15 pF)

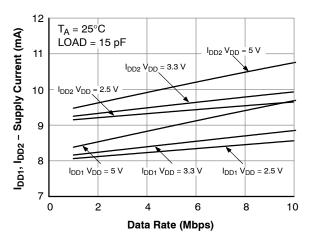


Figure 6. NCID9411 Supply Current vs. Data Rate (Load = 15 pF)

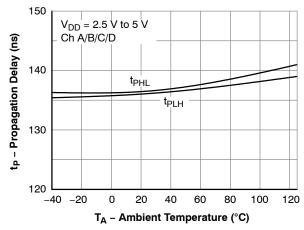


Figure 8. NCID9401 Propagation Delay vs. Ambient Temperature

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

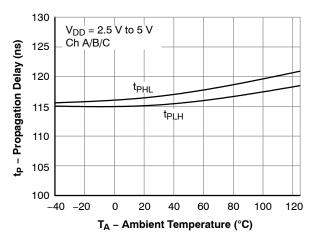


Figure 9. NCID9411 Channel A/B/C Propagation Delay vs. Ambient Temperature

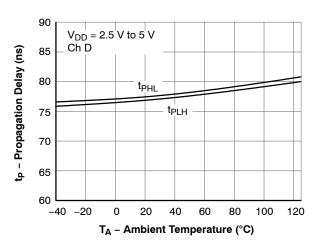


Figure 10. NCID9411 Channel D Propagation Delay vs.

Ambient Temperature

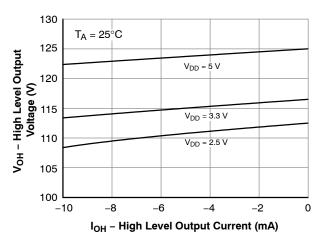


Figure 11. High Level Output Voltage vs. Current

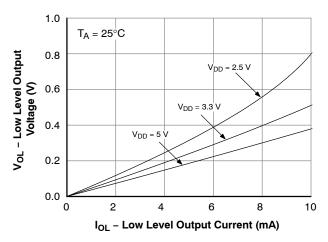


Figure 12. Low Level Output Voltage vs. Current

TEST CIRCUITS

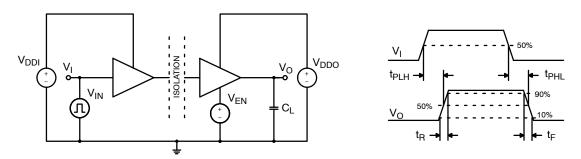


Figure 13. V_{IN} to V_{O} Propagation Delay Test Circuit and Waveform

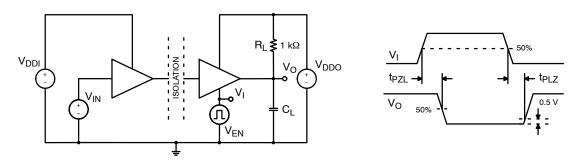


Figure 14. EN to Logic Low Vo Propagation Delay Test Circuit and Waveform

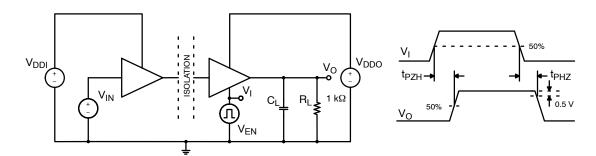


Figure 15. EN to Logic High V_O Propagation Delay Test Circuit and Waveform

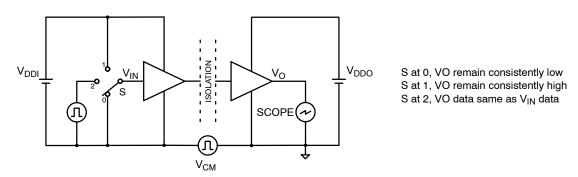


Figure 16. Common Mode Transient Immunity Test Circuit

APPLICATION INFORMATION

Theory of Operation

NCID9401 and NCID9411 are quad-channel digital isolators. Each channel enables communication between two isolated circuits. It uses off-chip ceramic capacitors that serve both as the isolation barrier and as the medium of transmission for signal switching using On-Off keying (OOK) technique, illustrated in the single channel operational block diagram in Figure 17.

At the transmitter side, the V_{IN} input logic state is modulated with a high frequency carrier signal. The resulting signal is amplified and transmitted to the isolation barrier. The receiver side detects the barrier signal and demodulates it using an envelope detection technique. The output signal determines the V_O output logic state when the output enable control EN is at high. When EN is at low, output V_O is at high impedance state. V_O is at default state low when the power supply at the transmitter side is turned off or the input V_{IN} is disconnected.

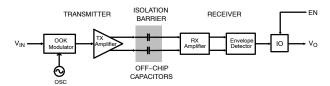


Figure 17. Operational Block Diagram of Single Channel

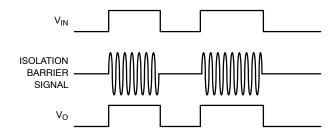


Figure 18. On-Off Keying Modulation Signals

Layout Recommendation

Layout of the digital circuits relies on good suppression of unwanted noise and electromagnetic interference. It is recommended to use 4–layer FR4 PCB, with ground plane below the components, power plane below the ground plane, signal lines and power fill on top, and signal lines and ground fill at the bottom. The alternating polarities of the layers creates interplane capacitances that aids the bypass capacitors required for reliable operation at digital switching rates.

In the layout with digital isolators, it is required that the isolated circuits have separate ground and power planes. The section below the device should be clear with no power, ground or signal traces. Maintain a gap equal to or greater than the specified minimum creepage clearance of the device package.

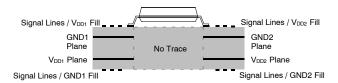


Figure 19. 4-Layer PCB for Digital Isolator

It is highly advised to connect at least a pair of low ESR supply bypass capacitors, placed within 2mm from the power supply pins 1 and 16 and ground pins 2 and 15. Recommended values are 1 μF and 0.1 μF , respectively. Place them between the V_{DD} pins of the device and the via to the power planes, with the higher frequency, lower value capacitor closer to the device pins. Directly connect the device ground pins 2, 8, 9 and 15 by via to their corresponding ground planes.

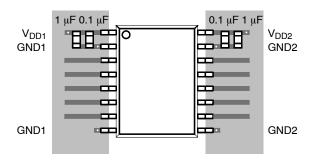


Figure 20. Placement of Bypass Capacitors

Over Temperature Detection

NCID9401 and NCID9411 have built—in Over Temperature Detection (OTD) feature that protects the IC from thermal damage. The output pins will automatically switch to default state when the ambient temperature exceeds the maximum junction temperature at threshold of approximately 160°C. The device will return to normal operation when the temperature decreases approximately 20°C below the OTD threshold.

ORDERING INFORMATION

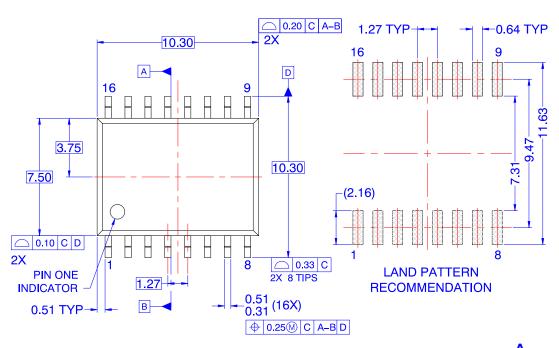
Part Number	Grade	Package	Shipping [†]
NCID9401	Industrial	SOIC16 W	50 Units / Tube
NCID9401R2	Industrial	SOIC16 W	750 Units / Tape & Reel
NCID9411	Industrial	SOIC16 W	50 Units / Tube
NCID9411R2	Industrial	SOIC16 W	750 Units / Tape & Reel
NCIV9401* (pending)	Automotive	SOIC16 W	50 Units / Tube
NCIV9401R2* (pending)	Automotive	SOIC16 W	750 Units / Tape & Reel
NCIV9411* (pending)	Automotive	SOIC16 W	50 Units / Tube
NCIV9411R2* (pending)	Automotive	SOIC16 W	750 Units / Tape & Reel

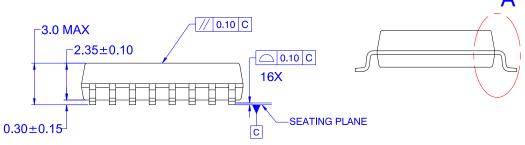
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

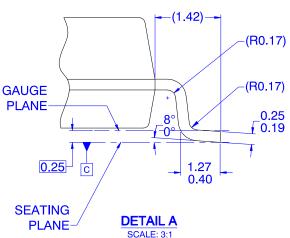
^{*}NCIV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

SOIC16 W CASE 751EN ISSUE O







NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING REFERS TO JEDEC MS-013, VARIATION AA.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS
- D) DRAWING CONFORMS TO ASME Y14.5M-1994
- E) LAND PATTERN STANDARD: SOIC127P1030X275-16N

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